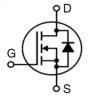


## X4-Class **Power MOSFET™**

# IXTP150N15X4 IXTH150N15X4

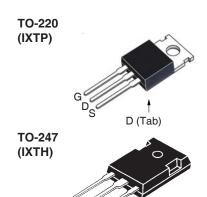
150V 150A  $7.2m\Omega$ 

N-Channel Enhancement Mode Avalanche Rated



Symbol	Test Conditions	Maximum Ratings			
V <sub>DSS</sub>	$T_J = 25^{\circ}C \text{ to } 175^{\circ}C$	150	V		
V <sub>DGR</sub>	$T_{_{\rm J}}$ = 25°C to 175°C, $R_{_{\rm GS}}$ = 1M $\Omega$	150	V		
V <sub>GSS</sub>	Continuous	±20	V		
V <sub>GSM</sub>	Transient	±30	V		
I <sub>D25</sub>	T <sub>C</sub> = 25°C	150	Α		
I <sub>DM</sub>	$T_{\rm C} = 25^{\circ}$ C, Pulse Width Limited by $T_{\rm JM}$	260	Α		
I <sub>A</sub>	T <sub>C</sub> = 25°C	75	Α		
E <sub>as</sub>	$T_{c} = 25^{\circ}C$	1	J		
dv/dt	$I_{_{\mathrm{S}}} \leq I_{_{\mathrm{DM}}}, V_{_{\mathrm{DD}}} \leq V_{_{\mathrm{DSS}}}, T_{_{\mathrm{J}}} \leq 150^{\circ}\mathrm{C}$	50	V/ns		
$P_{D}$	T <sub>C</sub> = 25°C	480	W		
T <sub>J</sub>		-55 +175	°C		
$T_{JM}$		175	°C		
T <sub>stg</sub>		-55 +175	°C		
T <sub>L</sub>	Maximum Lead Temperature for Soldering	300	°C		
T <sub>SOLD</sub>	1.6 mm (0.062in.) from Case for 10s	260	°C		
M <sub>d</sub>	Mounting Torque	1.13 / 10	Nm/lb.in		
Weight	TO-220 TO-247	3 6	g g		

10-241			0		
Symbol (T <sub>J</sub> = 25°C,	Test Conditions Unless Otherwise Specified)	Chara Min.	cteristic <sub> </sub> Typ.	Values   Max.	
BV <sub>DSS</sub>	$V_{GS} = 0V, I_D = 250\mu A$	150		V	
V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 250\mu A$	2.5		4.5 V	
I <sub>GSS</sub>	$V_{gs} = \pm 20V, V_{DS} = 0V$			±100 nA	
I <sub>DSS</sub>	$V_{DS} = V_{DSS}, V_{GS} = 0V$ $T_{J} = 150^{\circ}C$			10 μA 500 μA	
R <sub>ps(an)</sub>	V <sub>GS</sub> = 10V, I <sub>D</sub> = 0.5 • I <sub>DS</sub> , Note 1		6.2	7.2 mΩ	



G = Gate	D	=	Drain
S = Source	Tab	=	Drain

D (Tab)

## **Features**

- International Standard Packages
- Low R<sub>DS(ON)</sub> and Q<sub>G</sub>
   Avalanche Rated
- Low Package Inductance

## **Advantages**

- High Power Density
- Easy to Mount
- Space Savings

## **Applications**

- Switch-Mode and Resonant-Mode **Power Supplies**
- DC-DC Converters
- PFC Circuits
- AC and DC Motor Drives
- · Robotics and Servo Controls



Symbol	Test Conditions	Cha	racteristic	c Values
$(T_J = 25^{\circ}C)$	, Unless Otherwise Specified)	Min.	Тур.	Max
$\mathbf{g}_{fs}$	$V_{DS} = 10V, I_{D} = 60A, Note 1$	70	120	s
$R_{Gi}$	Gate Input Resistance		1.3	Ω
C <sub>iss</sub>			5500	pF
C <sub>oss</sub>	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		900	pF
C <sub>rss</sub>			4	pF
	Effective Output Capacitance			
$C_{o(er)}$	Energy related $V_{GS} = 0V$		660	pF
$C_{o(tr)}$	Time related $\int V_{DS} = 0.8 \cdot V_{DSS}$		2100	pF
t <sub>d(on)</sub>	Resistive Switching Times		23	ns
t,	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		5	ns
t <sub>d(off)</sub>	$R_{G} = 2\Omega$ (External)		60	ns
t <sub>f</sub>			6	ns
$Q_{g(on)}$			105	nC
$\mathbf{Q}_{gs}$	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		30	nC
$\mathbf{Q}_{gd}$			28	nC
R <sub>thJC</sub>				0.31 °C/W
R <sub>thCS</sub>	TO-220		0.50	°C/W
	TO-247		0.21	°C/W

## Source-Drain Diode

<b>Symbol</b> $(T_J = 25^{\circ}C, 10^{\circ})$	Test Conditions Unless Otherwise Specified)	Chara Min.	cteristic Typ.	Values Max	
I <sub>s</sub>	V <sub>GS</sub> = 0V			150	Α
I <sub>sm</sub>	Repetitive, pulse Width Limited by $T_{_{JM}}$			600	Α
V <sub>SD</sub>	$I_{\rm F} = 100 {\rm A}, \ V_{\rm GS} = 0 {\rm V}, \ {\rm Note} \ 1$			1.4	٧
$\left\{ egin{array}{c} \mathbf{t}_{rr} \\ \mathbf{Q}_{RM} \\ \mathbf{I}_{RM} \end{array} \right\}$	$I_{_{\rm F}} = 75 {\rm A},  -{\rm di}/{\rm dt} = 100 {\rm A}/\mu {\rm s}$ $V_{_{\rm R}} = 75 {\rm V}$		100 350 7		ns nC A

Note 1. Pulse test,  $t \le 300 \mu s$ , duty cycle,  $d \le 2\%$ .



Fig. 1. Output Characteristics @ T<sub>J</sub> = 25°C

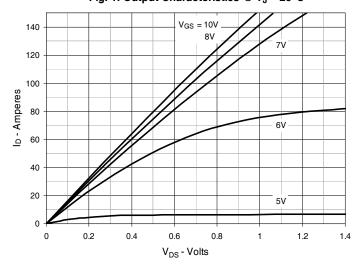


Fig. 2. Extended Output Characteristics @ T<sub>J</sub> = 25°C

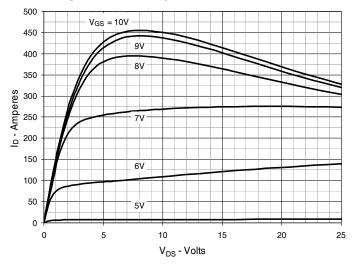


Fig. 3. Output Characteristics @ T<sub>J</sub> = 150°C

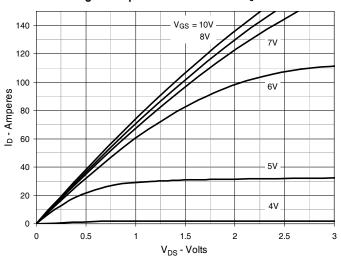


Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D$  = 75A Value vs.

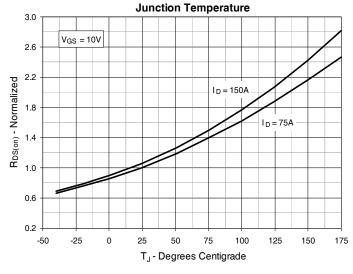


Fig. 5.  $R_{DS(on)}$  Normalized to  $I_D$  = 75A Value vs.

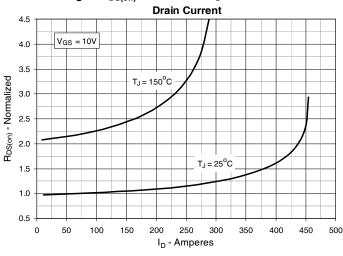
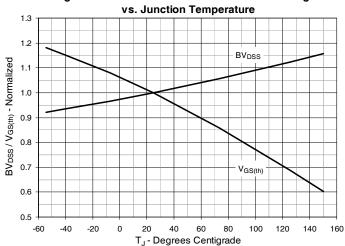
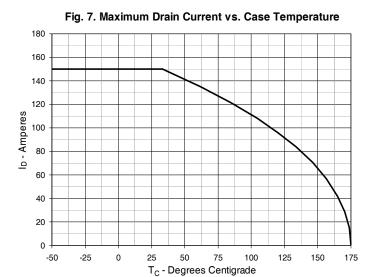
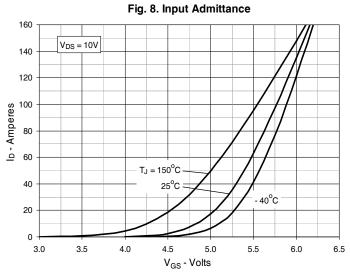


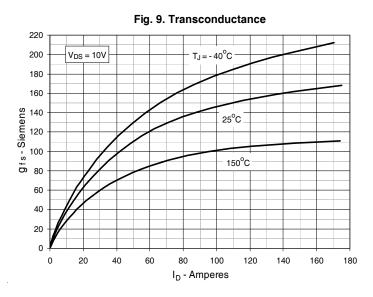
Fig. 6. Normalized Breakdown & Threshold Voltages

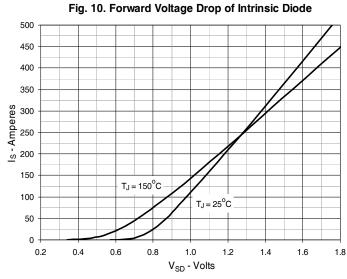


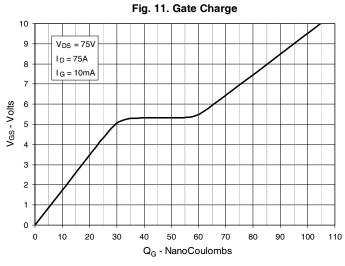


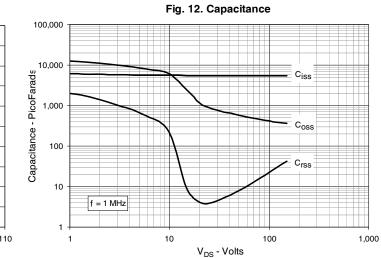






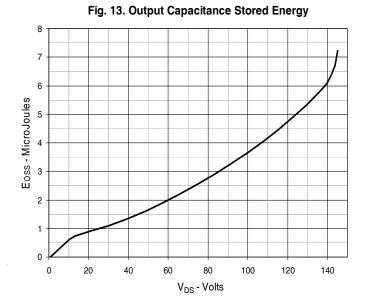






IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.







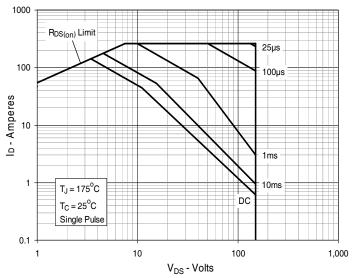
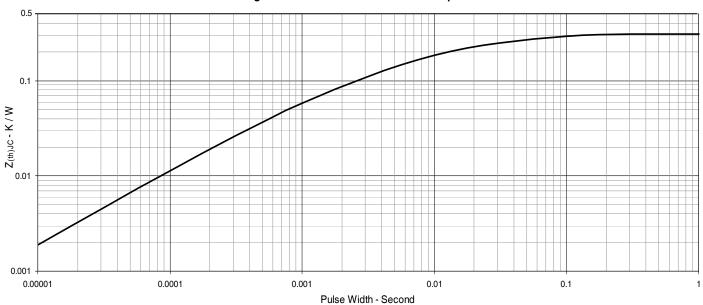
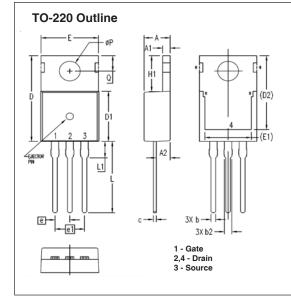


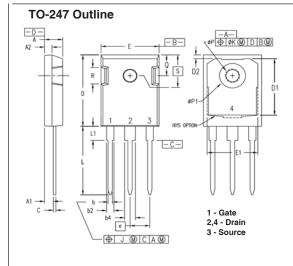
Fig. 15. Maximum Transient Thermal Impedance







SYM	INC	HES	MILLIM	ETERS	
2114	MIN	MAX	MIN	MAX	
Α	.169	.185	4.30	4.70	
A1	.047	.055	1.20	1.40	
A2	.079	.106	2.00	2.70	
Ь	.024	.039	0.60	1.00	
b2	.045	.057	1.15	1.45	
С	.014	.026	0.35	0.65	
D	.587	.626	14.90	15.90	
D1	.335	.370	8.50	9.40	
(D2)	.500	.531	12.70	13.50	
E	.382	.406	9.70	10.30	
(E1)	.283	.323	7.20	8.20	
е	.100	BSC	2.54 BSC		
e1	.200	.200 BSC		5.08 BSC	
H1	.244	.268	6.20	6.80	
L	.492	.547	12.50	13.90	
L1	.110	.154	2.80	3.90	
ØΡ	.134	.150	3.40	3.80	
Q	.106	.126	2.70	3.20	



SYM	INCH	łES	MILLIMETERS		
STIVI	MIN	MAX	MIN	MAX	
Α	.190	.205	4.83	5.21	
A1	.090	.100	2.29	2.54	
A2	.075	.085	1.91	2.16	
Ь	.045	.055	1.14	1.40	
b2	.075	.087	1.91	2.20	
b4	.115	.126	2.92	3.20	
С	.024	.031	0.61	0.80	
D	.819	.840	20.80	21.34	
D1	.650	.690	16.51	17.53	
D2	.035	.050	0.89	1.27	
E	.620	.635	15.75	16.13	
E1	.545	.565	13.84	14.35	
е	.215	BSC	5.45		
J		.010		0.25	
K		.025		0.64	
L	.780	.810	19.81	20.57	
L1	.150	.170	3.81	4.32	
øΡ	.140	.144	3.55	3.65	
øP1	.275	.290	6.99	7.37	
Q	.220	.244	5.59	6.20	
R	.170	.190	4.32	4.83	
S	.242	BSC	6.15 BSC		





Disclaimer Notice - Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at www.littelfuse.com/disclaimer-electronics.